

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

2SA1359

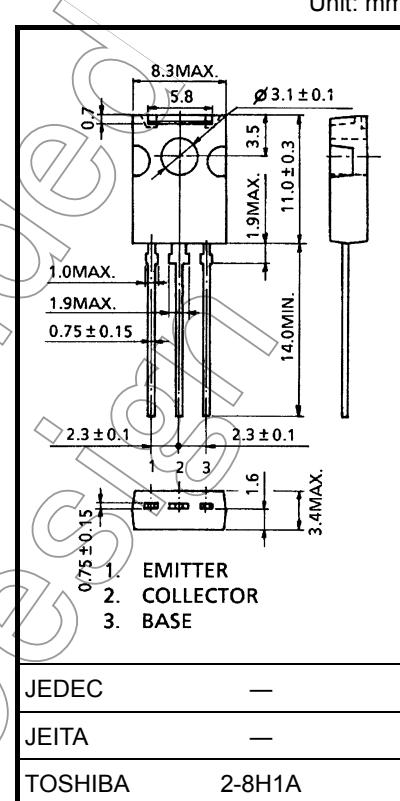
Audio Frequency Power Amplifier
Low-Speed Switching

- Suitable for the output stage of 5-watt car radios and car stereos.
- Good h_{FE} linearity
- Complementary to 2SC3422.

Absolute Maximum Ratings (T_c = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	-40	V
Collector-emitter voltage	V _{CEO}	-40	V
Emitter-base voltage	V _{EBO}	-5	V
Collector current	I _C	-3	A
Base current	I _B	-1	A
Collector power dissipation	P _C	1.5	W
Ta = 25°C			
Tc = 25°C		10	
Junction temperature	T _j	150	°C
Storage temperature range	T _{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Weight: 0.82 g (typ.)

Electrical Characteristics ($T_c = 25^\circ\text{C}$)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	$V_{CB} = -40\text{ V}, I_E = 0$	—	—	-100	nA
Emitter cut-off current	I_{EBO}	$V_{EB} = -5\text{ V}, I_C = 0$	—	—	-100	nA
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = -10\text{ mA}, I_B = 0$	-40	—	—	V
DC current gain	h_{FE} (1) (Note)	$V_{CE} = -2\text{ V}, I_C = -0.5\text{ A}$	80	—	240	
	h_{FE} (2)	$V_{CE} = -2\text{ V}, I_C = -2.5\text{ A}$	25	—	—	
Collector-emitter saturation voltage	$V_{CE(\text{sat})}$	$I_C = -2\text{ A}, I_B = -0.2\text{ A}$	—	—	-0.8	V
Base-emitter voltage	V_{BE}	$V_{CE} = -2\text{ V}, I_C = -0.5\text{ A}$	—	—	-1.0	V
Transition frequency	f_T	$V_{CE} = -2\text{ V}, I_C = -0.5\text{ A}$	—	100	—	MHz
Collector output capacitance	C_{ob}	$V_{CB} = -10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	35	—	pF

Note: h_{FE} (1) classification O: 80 to 160, Y: 120 to 240

Marking

